

# LS5114 P-CHANNEL JFET



# Linear Systems replaces discontinued Siliconix 2N5114

This analog switch is designed for inverting switching into inverting input of an Operational Amplifier.

The SOT-23 package provides ease of manufacturing, and a lower cost assembly option.

(See Packaging Information).

## LS5114 Benefits:

- Low On Resistance
- $I_{D(off)} \le 500 \text{ pA}$
- Switches directly from TTL logic

### LS5114 Applications:

- **Analog Switches**
- Commutators
- Choppers

FEATURES					
DIRECT REPLACEMENT FOR SILICONIX 2N5114					
LOW ON RESISTANCE	r <sub>DS(on)</sub> ≤ 75Ω				
LOW CAPACITANCE	6pF				
ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)					
Maximum Temperatures					
Storage Temperature	-55°C to +200°C				
Operating Junction Temperature	-55°C to +200°C				
Maximum Power Dissipation					
Continuous Power Dissipation	500mW				
MAXIMUM CURRENT	\$				
Gate Current (Note 1)	I <sub>G</sub> = -50mA				
MAXIMUM VOLTAGES					
Gate to Drain Voltage	V <sub>GDS</sub> = 30V				
Gate to Source Voltage	V <sub>GSS</sub> = 30V				

LS5114 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

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SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
$BV_{GSS}$	Gate to Source Breakdown Voltage	30				$I_{G} = 1\mu A, V_{DS} = 0V$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	4		10		$V_{DS} = -15V, I_{D} = -1nA$
$V_{GS(F)}$	Gate to Source Forward Voltage		-0.7	-1	V	$I_G = -1 \text{mA}, V_{DS} = 0 \text{V}$
			-1.0	-1.3		$V_{GS} = 0V, I_D = -15mA$
$V_{DS(on)}$	Drain to Source On Voltage		-0.7			$V_{GS} = 0V$ , $I_D = -7mA$
			-0.5			$V_{GS} = 0V$ , $I_D = -3mA$
I <sub>DSS</sub>	Drain to Source Saturation Current (Note 2)	-30		-90	mA	$V_{DS} = -18V, V_{GS} = 0V$
I <sub>GSS</sub>	Gate Reverse Current		5	500		$V_{GS} = 20V, \ V_{DS} = 0V$
I <sub>G</sub>	Gate Operating Current		-5			$V_{DS} = -15V, I_{D} = -1mA$
	Drain Cutoff Current		-10	-500	pΑ	$V_{DS} = -15V, V_{GS} = 12V$
I <sub>D(off)</sub>			-10			V <sub>DS</sub> = -15V, V <sub>GS</sub> = 7V
			-10	-		$V_{DS} = -15V, V_{GS} = 5V$
r <sub>DS(on)</sub>	Drain to Source On Resistance			75	Ω	$I_D = -1 \text{mA}, V_{GS} = 0 \text{V}$

LS5114 DYNAMIC ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
Forward Transconductance		4.5		mS	$V_{DS} = -15V, I_{D} = 1mA, f = 1kHz$
Output Conductance		20		μS	
Drain to Source On Resistance		-	75	Ω	$I_D = 0A$ , $V_{GS} = 0V$ , $f = 1kHz$
Input Capacitance		20	25		$V_{DS} = -15V$ , $V_{GS} = 0V$ , $f = 1MHz$
		5	7	pF	$V_{DS} = 0V, V_{GS} = 12V, f = 1MHz$
C <sub>rss</sub> Reverse Transfer Capacitance		6			$V_{DS} = 0V$ , $V_{GS} = 7V$ , $f = 1MHz$
		6			$V_{DS} = 0V$ , $V_{GS} = 5V$ , $f = 1MHz$
Equivalent Noise Voltage		20		nV/√Hz	$V_{DG} = 10V$ , $I_{D} = 10mA$ , $f = 1kHz$
	Output Conductance Drain to Source On Resistance Input Capacitance Reverse Transfer Capacitance	Output Conductance Drain to Source On Resistance Input Capacitance Reverse Transfer Capacitance	Output Conductance          20           Drain to Source On Resistance             Input Capacitance          20            5           Reverse Transfer Capacitance          6            6	Output Conductance          20            Drain to Source On Resistance           75           Input Capacitance          20         25            5         7           Reverse Transfer Capacitance          6             6	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

LS5114 SWITCHING CHARACTERISTICS @ 25°C (unless otherwise noted)

	SYMBOL	CHARACTERISTIC		UNITS	CONDITIONS
ĺ	t <sub>d(on)</sub>	Turn On Time	6		V <sub>GS</sub> (L) = -11V
Ì	t <sub>r</sub>	Turn On Rise Time	10	ns	V <sub>GS</sub> (H) = 0V
	t <sub>d(off)</sub>	Turn Off Time	6	113	See Switching Circuit
	t <sub>f</sub>	Turn Off Fall Time	15		·

Note 1 - Absolute maximum ratings are limiting values above which LS5114 serviceability may be impaired. Note 2 - Pulse test: PW≤ 300 µs, Duty Cycle ≤ 3%

#### **LS5114 SWITCHING CIRCUIT PARAMETERS**

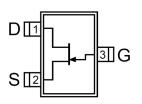
V <sub>DD</sub>	-10V
$V_{GG}$	20V
R <sub>L</sub>	430Ω
$R_{G}$	100Ω
I <sub>D(on)</sub>	-15mA

Micross Components Europe

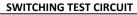
Available Packages:

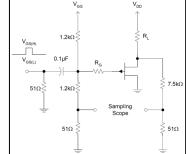
LS5114 in SOT-23 LS5114 in bare die.

Please contact Micross for full package and die dimensions



SOT-23 (Top View)







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